

In re Patent Application of:

**YAO**

Serial No. **10/736,859**

Filed: **DECEMBER 16, 2003**

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**In the Specification:**

Please replace the paragraph beginning at page 1, line 3, with the following rewritten paragraph:

[01] **Cross-Reference To Related Applications**

~~This application~~The present application is a continuation-in-part application of U.S. Patent Application No. 10/304,202, filed on November 26, 2002, and claims priority of U.S. Provisional Patent Application No. 60/333,616 filed on November 27, 2001, entitled "Doped Absorption for Enhanced Responsivity-Bandwidth Limit and Doped Quarternary Stack for the Reduction of Carrier Trapping in High-Speed High SensistivitySensitivity Photodiodes", and U.S. Patent Application No. 10/304,202 filed on November 26, 2002, which is incorporated herein by reference for all purposes.assigned to the assignee of the present application, and the disclosures of which are incorporated herein.